

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

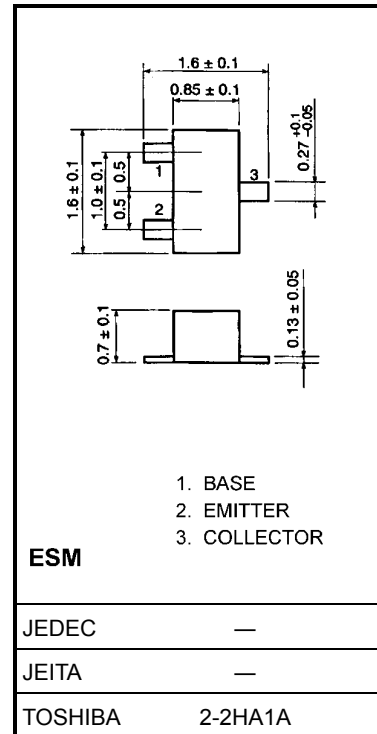
2SA1832F

Audio Frequency General Purpose Amplifier Applications

- High voltage and high current: $V_{CE0} = -50\text{ V}$, $I_C = -150\text{ mA}$ (max)
- Excellent h_{FE} linearity: $h_{FE}(I_C = -0.1\text{ mA})/h_{FE}(I_C = -2\text{ mA}) = 0.95$ (typ.)
- High h_{FE} : $h_{FE} = 120\sim 400$
- Complementary to 2SC4738F
- Small package

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CB0}	-50	V
Collector-emitter voltage	V_{CE0}	-50	V
Emitter-base voltage	V_{EB0}	-5	V
Collector current	I_C	-150	mA
Base current	I_B	-30	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	-55~125	°C



Electrical Characteristics (Ta = 25°C)

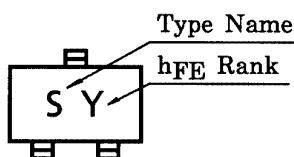
Weight: 2.3 mg (typ.)

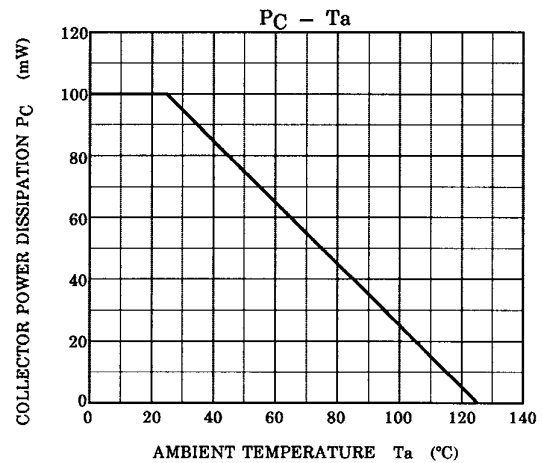
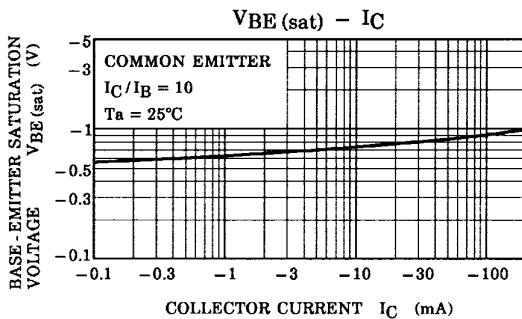
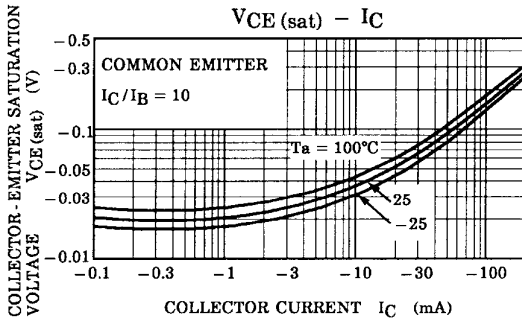
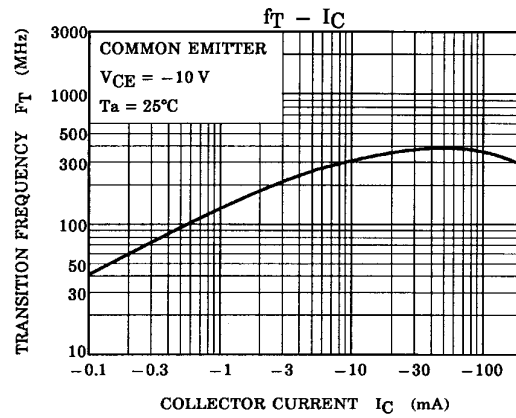
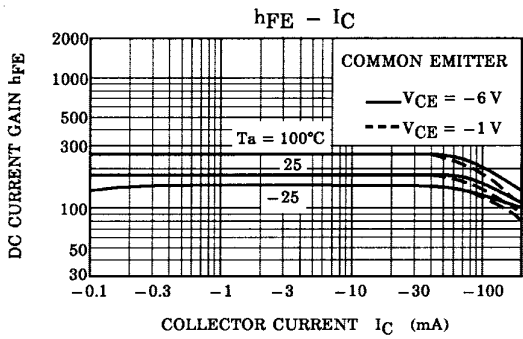
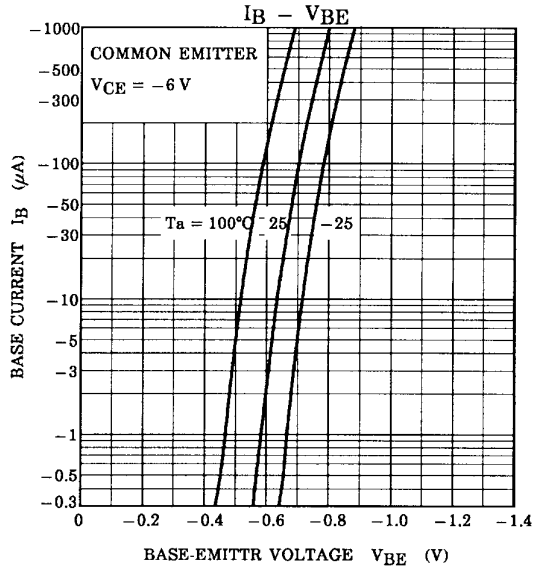
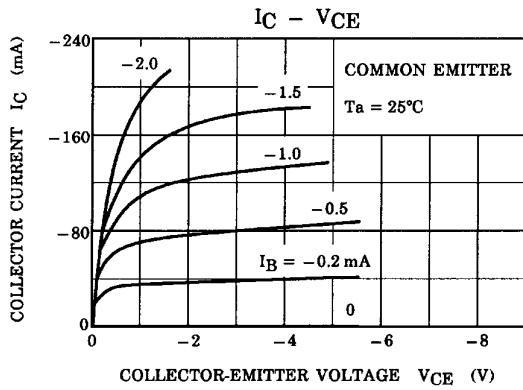
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CB0}	$V_{CB} = -50\text{ V}$, $I_E = 0$	—	—	-0.1	μA
Emitter cut-off current	I_{EB0}	$V_{EB} = -5\text{ V}$, $I_C = 0$	—	—	-0.1	μA
DC current gain	h_{FE} (Note)	$V_{CE} = -6\text{ V}$, $I_B = -2\text{ mA}$	120	—	400	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100\text{ mA}$, $I_B = -10\text{ mA}$	—	-0.1	-0.3	V
Transition frequency	f_T	$V_{CE} = -10\text{ V}$, $I_C = -1\text{ mA}$	80	—	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$	—	4	7	pF

Note: h_{FE} classification Y (Y): 120~240, GR (G): 200~400

() marking symbol

Marking





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